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Unitized Semiconductor Devices - Page 1 of 1



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Nelsure Material: Metal Overall Lenght: 2.00 Inches Terminal Lenght: 0.300 Inches Overall Diamote:: 0.370 Inches Data Electronic Davice Engineering Council/Jedec/ase Outline Designation: 7.77 Corponent Name And Quantity: 2 Tarrial Doming Method: Tarrial Terminal Terminal Cole Diameter: 0.200 Inches Partners Rovided: Battores Rovided: 1000 Interscret 0.2010 Indexer 2.2020 Inches Partners Rovided: 1000 Interscret 2.2030 Inches 2.2040 Inches 2.2050 Inches 2.0500 Inches <th>View Online at https://a</th> <th>aerobasegroup.com/nsn/5961-01-177-1335</th>	View Online at https://a	aerobasegroup.com/nsn/5961-01-177-1335
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